

✓ Please substitute the paragraph starting at page 25, line 1 and ending at line 3, with the following paragraph. A marked-up copy of the paragraph, showing the changes made thereto, is attached.

1323 --Next, an example of a method for fabricating a semiconductor device by utilizing the projection exposure apparatus explained in Fig. 6 will be described.--

REMARKS

Claims 1-21 remain pending in the present application. Claims 1, 8, 16, 17, 19, and 20 are the independent claims.

The specification has been amended to correct minor informalities and to improve its idiomatic English form.

By separate paper filed concurrently herewith, Applicants seek the Examiner's approval to amend Figures 2A and 3 of the drawings. Favorable consideration is requested.

Due consideration and prompt passage to issue are respectfully requested.

Applicants' undersigned attorney may be reached in our Washington, D.C.
office by telephone at (202) 530-1010. All correspondence should continue to be directed
to our below-listed address.

Respectfully submitted,



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